UNISONIC TECHNOLOGIES CO., LTD

UG1N120

Preliminary

Insulated Gate Bipolar Transistor

5.3A, 1200V NPT SERIES N-CHANNEL IGBT

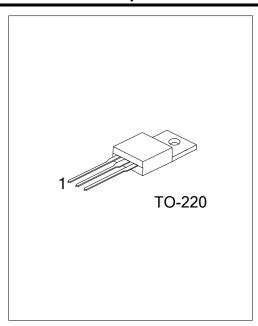
DESCRIPTION

The UTC UG1N120 is a NPT series N-Channel IGBT, it uses UTC's advanced technology to provide the customers with a minimum on-state resistance, etc.

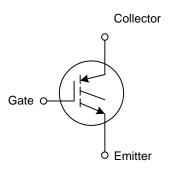
The UTC UG1N120 is suitable for AC and DC motor controls, power supplies, and drivers for solenoids, relays and contactors, etc.

FEATURES

- * Low conduction loss
- * Short circuit rating



SYMBOL

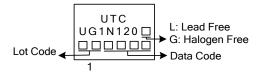


ORDERING INFORMATION

Ordering Number		Dooleana	Pin	Assignn	Deeldes		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UG1N120L-TA3-T	UG1N120G-TA3-T	TO-220	G	С	Е	Tube	

E: Emitter Note: Pin Assignment: G: Gate C: Collector UG1N120L-TA3-T (1) T: Tube (1)Packing Type (2)Package Type (2) TA3: TO-220 (3)Green Package (3) L: Lead Free, G: Halogen Free and Lead Free

MARKING



www.unisonic.com.tw 1 of 3

■ ABSOLUTE MAXIMUM RATING (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Emitter Voltage	BV _{CES}	1200	V
Gate to Emitter Voltage Continuous	$V_{\sf GES}$	±20	V
Gate to Emitter Voltage Pulsed	V_{GEM}	±30	V
Collector Current Continuous	Ic	5.3	Α
Collector Current Continuous $T_c=110^{\circ}C$		2.7	Α
Collector Current Pulsed (Note 1)	I _{CM}	6	Α
Power Dissipation Total at T _C =25°C	P_D	60	W
Power Dissipation Derating T _C >25°C		0.476	W/°C
Forward Voltage Avalanche Energy (Note 2)	E _{AV}	10	mJ
Short Circuit Withstand Time (Note 3) at V _{GE} =15V	t _{SC}	8	μs
Short Circuit Withstand Time (Note 3) at V _{GE} =12V	t _{SC}	13	μs
Operating Junction Temperature Range	ΤJ	-55~+150	°C
Storage Temperature Range	T _{STG}	-55~+150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by maximum junction temperature.
- 3. I_{CE} =7A, L=400 μ H, V_{GE} =15V, T_{J} =25°C.
- 4. $V_{CE(PK)}$ =840V, T_J =125°C, R_G =82 Ω .

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	2.1	°C/W

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Collector to Emitter Breakdown Voltage	BV _{CES}	I _C =250μA, V _{GE} =0V		1200			V
Emitter to Collector Breakdown Voltage	BV _{ECS}	I _C =10mA, V _{GE} =0V		15			V
Collector to Emitter Leakage Current	I _{CES}	V _{CE} =1200V	T _C =25°C			250	μA
			T _C =125°C		20		μΑ
			T _C =150°C			1.0	mA
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =1.0A, V _{GE} =15V	T _C =25°C		2.5	2.9	V
			T _C =150°C		3.8	4.3	V
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	$I_C=50\mu A, V_{CE}=V_{GE}$		6.0	7.1		V
Gate to Emitter Leakage Current	I _{GES}	V _{GE} =±20V				±250	nA
Switching SOA	SSOA	$T_J=150^{\circ}C$, $R_G=82\Omega$, $V_{GE}=15V$, $L=2mH$, $V_{CE(PK)}=1200V$		6			Α
Gate to Emitter Plateau Voltage	V_{GEP}	I _C =1.0A, V _{CE} =600V			9.2		٧
On-State Gate Charge	Q _{G(ON)}	I _C =1.0A, V _{CE} =600V	V _{GE} =15V		14	20	nC
			V _{GE} =20V		15	21	nC
Current Turn-On Delay Time	t _{d(ON)I}	IGBT and Diode at T_J =25°C I_{CE} =1.0A, V_{CE} =30V, V_{GE} =15V, R_G =82 Ω			200		ns
Current Rise Time	t _{rl}				470		ns
Current Turn-Off Delay Time	t _{d(OFF)I}				118		ns
Current Fall Time	t _{fl}				200		ns

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